

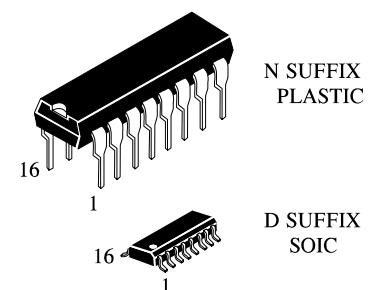
8-INPUT DATA SELECTOR/MUX

High-Performance Silicon-Gate CMOS

The IN74HC151 is identical in pinout to the LS/ALS151. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LS/ALSTTL outputs.

The device selects one of the eight binary Data Inputs, as determined by the Address Inputs. The Strobe pin must be at a low level for the selected data to appear at the outputs. If Strobe is high, the Y output is forced to a low level and the \bar{Y} output is forced to a high level.

- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 μ A
- High Noise Immunity Characteristic of CMOS Devices



ORDERING INFORMATION

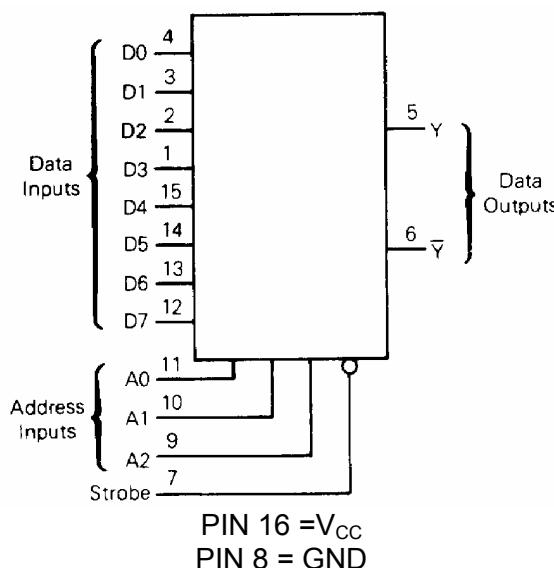
IN74HC151N Plastic
IN74HC151D SOIC

$T_A = -55^\circ$ to 125° C for all packages

PIN ASSIGNMENT

D3	1 ●	16	V _{CC}
D2	2	15	D4
D1	3	14	D5
D0	4	13	D6
Y	5	12	D7
\bar{Y}	6	11	A0
STROBE	7	10	A1
GND	8	9	A2

LOGIC DIAGRAM



FUNCTION TABLE

Inputs				Outputs	
A2	A1	A0	Strobe	Y	\bar{Y}
X	X	X	H	L	H
L	L	L	L	D0	$\bar{D}0$
L	L	H	L	D1	$\bar{D}1$
L	H	L	L	D2	$\bar{D}2$
L	H	H	L	D3	$\bar{D}3$
H	L	L	L	D4	$\bar{D}4$
H	L	H	L	D5	$\bar{D}5$
H	H	L	L	D6	$\bar{D}6$
H	H	H	L	D7	$\bar{D}7$

D0,D1...D7=the level of the respective D input
X = don't care



MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)	-1.5 to V_{CC} +1.5	V
V_{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
I_{IN}	DC Input Current, per Pin	± 20	mA
I_{OUT}	DC Output Current, per Pin	± 25	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	± 50	mA
P_D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package : - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V_{CC}	V
T_A	Operating Temperature, All Package Types	-55	+125	°C
t_r, t_f	Input Rise and Fall Time (Figure 1) $V_{CC} = 2.0$ V $V_{CC} = 4.5$ V $V_{CC} = 6.0$ V	0 0 0	1000 500 400	ns

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

IN74HC151

DC ELECTRICAL CHARACTERISTICS(Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				25 °C to -55°C	≤85 °C	≤125 °C	
V_{IH}	Minimum High-Level Input Voltage	$V_{OUT}=0.1\text{ V}$ or $V_{CC}-0.1\text{ V}$ $ I_{OUT} \leq 20\text{ }\mu\text{A}$	2.0	1.5	1.5	1.5	V
			4.5	3.15	3.15	3.15	
			6.0	4.2	4.2	4.2	
V_{IL}	Maximum Low - Level Input Voltage	$V_{OUT}=0.1\text{ V}$ or $V_{CC}-0.1\text{ V}$ $ I_{OUT} \leq 20\text{ }\mu\text{A}$	2.0	0.3	0.3	0.3	V
			4.5	0.9	0.9	0.9	
			6.0	1.2	1.2	1.2	
V_{OH}	Minimum High-Level Output Voltage	$V_{IN}=V_{IH}$ or V_{IL} $ I_{OUT} \leq 20\text{ }\mu\text{A}$	2.0	1.9	1.9	1.9	V
			4.5	4.4	4.4	4.4	
			6.0	5.9	5.9	5.9	
		$V_{IN}=V_{IH}$ or V_{IL} $ I_{OUT} \leq 4.0\text{ mA}$ $ I_{OUT} \leq 5.2\text{ mA}$	4.5	3.98	3.84	3.7	
V_{OL}	Maximum Low-Level Output Voltage	$V_{IN}=V_{IH}$ or V_{IL} $ I_{OUT} \leq 20\text{ }\mu\text{A}$	2.0	0.1	0.1	0.1	V
			4.5	0.1	0.1	0.1	
			6.0	0.1	0.1	0.1	
		$V_{IN}=V_{IH}$ or V_{IL} $ I_{OUT} \leq 4.0\text{ mA}$ $ I_{OUT} \leq 5.2\text{ mA}$	4.5	0.26	0.33	0.4	
I_{IN}	Maximum Input Leakage Current	$V_{IN}=V_{CC}$ or GND	6.0	± 0.1	± 1.0	± 1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	$V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu\text{A}$	6.0	8.0	80	160	μA

AC ELECTRICAL CHARACTERISTICS($C_L=50\text{pF}$,Input $t_r=t_f=6.0\text{ ns}$)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			25 °C to -55°C	≤85°C	≤125 °C	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Input D to Output Y or \bar{Y} (Figures 1,3 and 6)	2.0	185	230	280	ns
		4.5	37	46	56	
		6.0	31	39	48	
t_{PLH}, t_{PHL}	Maximum Propagation Delay , Input A to Output Y or \bar{Y} (Figures 2 and 6)	2.0	205	255	310	ns
		4.5	41	51	62	
		6.0	35	43	53	
t_{PLH}, t_{PHL}	Maximum Propagation Delay , Strobe to Output Y or \bar{Y} (Figures 4,5 and 6)	2.0	125	155	190	ns
		4.5	25	31	38	
		6.0	21	26	32	
t_{TLH}, t_{THL}	Maximum Output Transition Time, Any Output (Figures 1 and 6)	2.0	75	95	110	ns
		4.5	15	19	22	
		6.0	13	16	19	
C_{IN}	Maximum Input Capacitance	-	10	10	10	pF

C_{PD}	Power Dissipation Capacitance (Per Package) Used to determine the no-load dynamic power $P_D=C_{PD}V_{CC}^2f+I_{CC}V_{CC}$	Typical @25°C, $V_{CC}=5.0\text{ V}$	pF
		36	

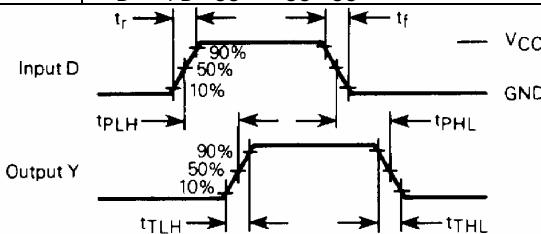


Figure 1. Switching Waveforms

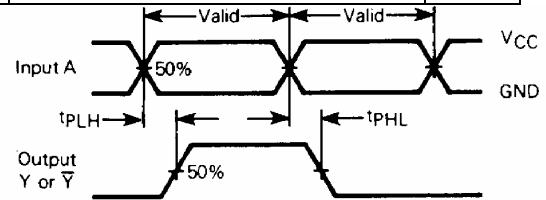


Figure 2. Switching Waveforms

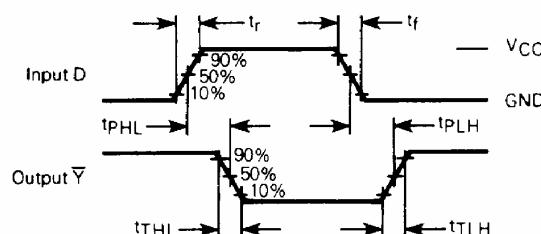


Figure 3. Switching Waveforms

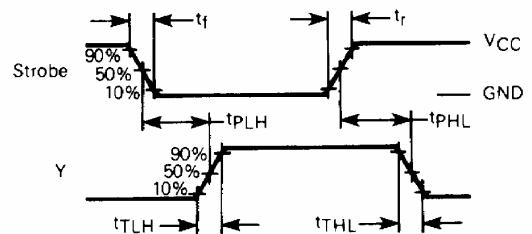


Figure 4. Switching Waveforms

IN74HC151

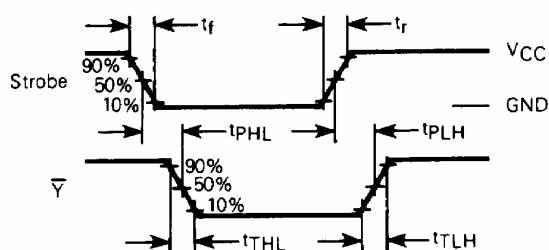


Figure 5. Switching waveforms

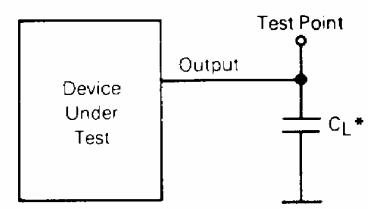


Figure 6. Test Circuit

EXPANDED LOGIC DIAGRAM

